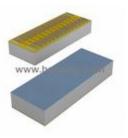




EPC2020ENGR Information



For Reference Only

Part Number EPC2020ENGR

Manufacturer EPC

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description TRANS GAN 60V 60A BUMPED DIE

Package Die

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









EPC2020ENGR Specifications

Manufacturer Part Number	EPC2020ENGR
Manufacturer	EPC
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	Die
Series	eGaN?
FET Type	N-Channel
Technology	GaNFET (Gallium Nitride)
Drain to Source Voltage (Vdss)	60V
Current - Continuous Drain (Id) @ 25°C	60A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	5V
Vgs(th) (Max) @ Id	2.5V @ 16mA
Gate Charge (Qg) (Max) @ Vgs	16nC @ 5V
Input Capacitance (Ciss) (Max) @ Vds	1800pF @ 30V
Vgs (Max)	+6V, -4V
FET Feature	-
Power Dissipation (Max)	-
Rds On (Max) @ Id, Vgs	2.2 mOhm @ 31A, 5V
Operating Temperature	-40°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	Die
Package / Case	Die
	Report errors?

EPC2020ENGR Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

EPC2020ENGR Payment Methods



















EPC2020ENGR Shipping Methods













If you have any question about EPC2020ENGR, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com